



**THE DATASHEET OF
ADUM5211CRSZ-RL7**



ADuM5210/ADuM5211/ADuM5212

Dual-Channel Isolators with Integrated DC-to-DC Converters

FEATURES

- ▶ isoPower integrated, isolated dc-to-dc converter
- ▶ Regulated 3.135 V to 5.25 V output
- ▶ Up to 150 mW output power
- ▶ Dual dc-to-100 Mbps (NRZ) signal isolation channels
- ▶ Soft start power supply
- ▶ 20-lead SSOP package with 5.3 mm creepage
- ▶ Supports SPI up to 15 MHz
- ▶ High temperature operation: 105°C
- ▶ High common-mode transient immunity: >25 kV/μs
- ▶ Safety and regulatory approvals
 - ▶ UL 1577
 - ▶ $V_{ISO} = 2500$ V rms for 1 minute
 - ▶ IEC/CSA 62368-1
 - ▶ IEC/CSA 61010-1
 - ▶ CQC GB 4943.1
 - ▶ DIN EN IEC 60747-17 (VDE 0884-17)
 - ▶ $V_{IORM} = 600$ V peak

APPLICATIONS

- ▶ RS-232 transceivers
- ▶ Power supply start-up bias and gate drives
- ▶ Isolated sensor interfaces
- ▶ Industrial PLCs

GENERAL DESCRIPTION

The ADuM5210/ADuM5211/ADuM5212¹ are dual-channel digital isolators with isoPower®, an integrated, isolated dc-to-dc converter. Based on the Analog Devices, Inc., iCoupler® technology, the dc-to-dc converter provides regulated, isolated power that is adjustable between 3.135 V and 5.25 V. Input supply voltages can range from slightly below the required output to significantly higher. Popular voltage combinations and their associated power levels are shown in Table 2.

The ADuM5210/ADuM5211/ADuM5212 eliminate the need for a separate, isolated dc-to-dc converter in low power, isolated designs. The iCoupler chip-scale transformer technology is used for isolated logic signals and for the magnetic components of the dc-to-dc converter. The result is a small form factor, total isolation solution.

isoPower uses high frequency switching elements to transfer power through its transformer. Take special care during printed circuit board (PCB) layout to meet emissions standards. See the AN-0971 Application Note for board layout recommendations.

FUNCTIONAL BLOCK DIAGRAM

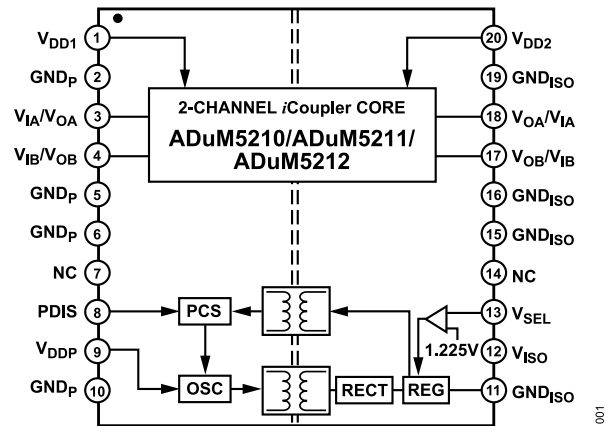


Figure 1. ADuM5210/ADuM5211/ADuM5212

Table 1. Data Input/Output (I/O) Port Assignments

| Channel | Pin | ADuM5210 | ADuM5211 | ADuM5212 |
|-----------------|-----|----------|----------|----------|
| V_{IA}/V_{OA} | 3 | V_{IA} | V_{OA} | V_{OA} |
| V_{IB}/V_{OB} | 4 | V_{IB} | V_{IB} | V_{OB} |
| V_{OA}/V_{IA} | 18 | V_{OA} | V_{IA} | V_{IA} |
| V_{OB}/V_{IB} | 17 | V_{OB} | V_{OB} | V_{IB} |

Table 2. Power Levels

| Input Voltage (V) | Output Voltage (V) | Output Power (mW) |
|-------------------|--------------------|-------------------|
| 5 | 5 | 150 |
| 5 | 3.3 | 100 |
| 3.3 | 3.3 | 66 |

¹ Protected by U.S. Patents 5,952,849; 6,873,065; 6,903,578; and 7,075,329. Other patents are pending.

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REVISION HISTORY**10/2025—Rev. E to Rev. F**

| | |
|----------------------------------|----|
| Changes to Features Section..... | 1 |
| Changes to Table 16..... | 8 |
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11/2024—Rev. D to Rev. E

| | |
|---|----|
| Changes to Features Section..... | 1 |
| Changed Regulatory Approvals Section to Regulatory Information Section..... | 8 |
| Changes to Regulatory Information Section and Table 16..... | 8 |
| Changes to Insulation and Safety-Related Specifications Section and Table 17..... | 8 |
| Changed DIN V VDE V 0884-10 (VDE V 0884-10) Insulation Characteristics Section to DIN EN IEC 60747-17 (VDE 0884-17) Insulation Characteristics Section..... | 9 |
| Changes to DIN EN IEC 60747-17 (VDE 0884-17) Insulation Characteristics Section, Table 18, and Figure 2 Caption..... | 9 |
| Deleted Table 21; Renumbered Sequentially..... | 11 |
| Changes to Insulation Lifetime Section..... | 20 |

SPECIFICATIONS

ELECTRICAL CHARACTERISTICS—5 V PRIMARY INPUT SUPPLY/5 V SECONDARY ISOLATED SUPPLY

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = V_{DDP} = 5\text{ V}$, V_{SEL} resistor network: $R_1 = 10\text{ k}\Omega$, $R_2 = 30.9\text{ k}\Omega$ between V_{ISO} and GND_{ISO} . Minimum/maximum specifications apply over the entire recommended operation range, which is $4.5\text{ V} \leq V_{DD1}, V_{DD2}, V_{DDP} \leq 5.5\text{ V}$ and $-40^\circ\text{C} \leq T_A \leq +105^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 3. DC-to-DC Converter Static Specifications

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|----------------------------------|------------------|-------|-----|-------|------------------------------|---|
| DC-TO-DC CONVERTER SUPPLY | | | | | | |
| Setpoint | V_{ISO} | 4.675 | 5.0 | 5.325 | V | $I_{ISO} = 15\text{ mA}$, $R_1 = 10\text{ k}\Omega$, $R_2 = 30.9\text{ k}\Omega$ |
| Thermal Coefficient | $V_{ISO(TC)}$ | | -44 | | $\mu\text{V}/^\circ\text{C}$ | |
| Line Regulation | $V_{ISO(LINE)}$ | | 20 | | mV/V | $I_{ISO} = 15\text{ mA}$, $V_{DDP} = 4.5\text{ V}$ to 5.5 V |
| Load Regulation | $V_{ISO(LOAD)}$ | | 1.3 | 3 | % | $I_{ISO} = 3\text{ mA}$ to 27 mA |
| Output Ripple | $V_{ISO(RIP)}$ | | 75 | | mV p-p | 20 MHz bandwidth, $C_{BO} = 0.1\text{ }\mu\text{F} 10\text{ }\mu\text{F}$, $I_{ISO} = 27\text{ mA}$ |
| Output Noise | $V_{ISO(NOISE)}$ | | 200 | | mV p-p | $C_{BO} = 0.1\text{ }\mu\text{F} 10\text{ }\mu\text{F}$, $I_{ISO} = 27\text{ mA}$ |
| Switching Frequency | f_{OSC} | | 125 | | MHz | |
| Pulse-Width Modulation Frequency | f_{PWM} | | 600 | | kHz | |
| Output Supply | $I_{ISO(MAX)}$ | 30 | | | mA | $5.5\text{ V} > V_{ISO} > 4.5\text{ V}$ |
| Efficiency at $I_{ISO(MAX)}$ | | | 29 | | % | $I_{ISO} = 27\text{ mA}$ |
| I_{DDP} , No V_{ISO} Load | $I_{DDP(Q)}$ | | 6.8 | 12 | mA | |
| I_{DDP} , Full V_{ISO} Load | $I_{DDP(MAX)}$ | | 104 | | mA | |
| Thermal Shutdown | | | | | | |
| Shutdown Temperature | | | 154 | | $^\circ\text{C}$ | |
| Thermal Hysteresis | | | 10 | | $^\circ\text{C}$ | |

Table 4. Data Channel Supply Current

| Parameter | Symbol | 1 Mbps—A, B, C Grades | | | 25 Mbps—B, C Grades | | | 100 Mbps—C Grade | | | Unit | Test Conditions/Comments |
|----------------|-----------|-----------------------|-----|-----|---------------------|-----|-----|------------------|------|-----|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SUPPLY CURRENT | | | | | | | | | | | | |
| ADuM5210 | I_{DD1} | | 1.1 | 1.6 | | 6.2 | 7.0 | | 20 | 25 | mA | $C_L = 0\text{ pF}$ |
| | I_{DD2} | | 2.7 | 4.5 | | 4.8 | 7.0 | | 9.5 | 15 | mA | $C_L = 0\text{ pF}$ |
| ADuM5211 | I_{DD1} | | 2.1 | 2.7 | | 4.9 | 6.5 | | 15 | 19 | mA | $C_L = 0\text{ pF}$ |
| | I_{DD2} | | 2.3 | 2.9 | | 4.7 | 6.5 | | 15.6 | 19 | mA | $C_L = 0\text{ pF}$ |
| ADuM5212 | I_{DD1} | | 2.7 | 4.5 | | 4.8 | 7.0 | | 9.5 | 15 | mA | $C_L = 0\text{ pF}$ |
| | I_{DD2} | | 1.1 | 1.6 | | 6.2 | 7.0 | | 20 | 25 | mA | $C_L = 0\text{ pF}$ |

Table 5. Switching Specifications

| Parameter | Symbol | A Grade | | | B Grade | | | C Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|---------|-----|-----|---------|-----|-----|---------|-----|-----|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 25 | | | 100 | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | | | 50 | | | 35 | 20 | 23 | 29 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | 10 | | | 3 | | | 2 | ns | $ t_{PLH} - t_{PHL} $ |
| Pulse Width | PW | 1000 | | | 40 | | | 10 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 38 | | | 12 | | | 9 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 5 | | | 3 | | | 2 | ns | |
| Opposing Direction | t_{PSKOD} | | | 10 | | | 6 | | | 5 | ns | |
| Jitter | | | 2 | | | 2 | | | 1 | | ns | |

SPECIFICATIONS

Table 6. Input and Output Characteristics

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----------------------------------|-------|-----------------------------------|-------------------------------|---|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | 0.7 V_{ISO} , 0.7 V_{DD1} | | | V | |
| Logic Low Input Threshold | V_{IL} | | | | 0.3 V_{ISO} , 0.3 V_{DD1} | V |
| Logic High Output Voltages | V_{OH} | $V_{DD1} - 0.1$, $V_{DD2} - 0.1$ | | V_{DD1} , V_{DD2} | V | $I_{Ox} = -20 \mu A$, $V_{Ix} = V_{IxH}$ |
| | | $V_{DD1} - 0.4$, $V_{DD2} - 0.4$ | | $V_{DD1} - 0.2$, $V_{DD2} - 0.2$ | V | $I_{Ox} = -3.2 \text{ mA}$, $V_{Ix} = V_{IxH}$ |
| Logic Low Output Voltages | V_{OL} | 0.0 | | 0.1 | V | $I_{Ox} = 20 \mu A$, $V_{Ix} = V_{IxL}$ |
| | | 0.2 | | 0.4 | V | $I_{Ox} = 3.2 \text{ mA}$, $V_{Ix} = V_{IxL}$ |
| Undervoltage Lockout | | | | | V | V_{DD1} , V_{DD2} , V_{DDP} supply |
| Positive Going Threshold | V_{UV+} | 2.6 | | | V | |
| Negative Going Threshold | V_{UV-} | 2.4 | | | V | |
| Hysteresis | V_{UVH} | 0.2 | | | V | |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DDI(Q)}$ | 0.54 | | 0.8 | mA | |
| Quiescent Output Supply Current | $I_{DDO(Q)}$ | 1.6 | | 2.0 | mA | |
| Dynamic Input Supply Current | $I_{DDI(D)}$ | 0.09 | | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DDO(D)}$ | 0.04 | | | mA/Mbps | |
| Input Currents per Channel | I_I | -10 | +0.01 | +10 | μA | $0 \text{ V} \leq V_{Ix} \leq V_{DDx}$ |
| AC SPECIFICATIONS | | | | | | |
| Output Rise/Fall Time | t_R/t_F | 2.5 | | | ns | 10% to 90% |
| Common-Mode Transient Immunity ¹ | CM | 25 | 35 | | kV/ μs | $V_{Ix} = V_{DD1}$ or V_{ISO} , $V_{CM} = 1000 \text{ V}$, transient magnitude = 800 V |
| Refresh Rate | t_r | 1.6 | | | μs | |

¹ |CM| is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_{Ox} > 0.8 \times V_{DD1}$ or $0.8 \times V_{ISO}$ for a high input or $V_{Ox} < 0.8 \times V_{DD1}$ or $0.8 \times V_{ISO}$ for a low input. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—3.3 V PRIMARY INPUT SUPPLY/3.3 V SECONDARY ISOLATED SUPPLY

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DD2} = V_{DDP} = 3.3 \text{ V}$, V_{SEL} resistor network: $R1 = 10 \text{ k}\Omega$, $R2 = 16.9 \text{ k}\Omega$ between V_{ISO} and GND_{ISO} . Minimum/maximum specifications apply over the entire recommended operation range, which is $3.135 \text{ V} \leq V_{DD1}$, V_{DD2} , $V_{DDP} \leq 3.6 \text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +105^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15 \text{ pF}$ and CMOS signal levels, unless otherwise noted.

The digital isolator channels and the power section work independently, and under the operating voltages in this section, there may not be sufficient current from the V_{ISO} to run both data channels at the maximum data rate. Verify that the application is within the power capability of V_{ISO} if that supply is providing power to V_{DD2} .

Table 7. DC-to-DC Converter Static Specifications

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---------------------------|-------------------|-------|-----|------|------------------------|---|
| DC-TO-DC CONVERTER SUPPLY | | | | | | |
| Setpoint | V_{ISO} | 3.135 | 3.3 | 3.51 | V | $I_{ISO} = 10 \text{ mA}$, $R1 = 10 \text{ k}\Omega$, $R2 = 16.9 \text{ k}\Omega$ |
| Thermal Coefficient | $V_{ISO} (TC)$ | -26 | | | $\mu V/^\circ\text{C}$ | $I_{ISO} = 20 \text{ mA}$ |
| Line Regulation | $V_{ISO} (LINE)$ | 20 | | | mV/V | $I_{ISO} = 10 \text{ mA}$, $V_{DDP} = 3.135 \text{ V}$ to 3.6 V |
| Load Regulation | $V_{ISO} (LOAD)$ | 1.3 | | 3 | % | $I_{ISO} = 2 \text{ mA}$ to 18 mA |
| Output Ripple | $V_{ISO} (RIP)$ | 50 | | | mV p-p | 20 MHz bandwidth, $C_{BO} = 0.1 \mu F 10 \mu F$, $I_{ISO} = 18 \text{ mA}$ |
| Output Noise | $V_{ISO} (NOISE)$ | 130 | | | mV p-p | $C_{BO} = 0.1 \mu F 10 \mu F$, $I_{ISO} = 18 \text{ mA}$ |

SPECIFICATIONS

Table 7. DC-to-DC Converter Static Specifications (Continued)

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|----------------------------------|-----------------|-----|-----|------|------|-----------------------------|
| Switching Frequency | f_{OSC} | | 125 | | MHz | |
| Pulse-Width Modulation Frequency | f_{PWM} | | 600 | | kHz | |
| Output Supply | $I_{ISO (MAX)}$ | 20 | | | mA | $3.6 V > V_{ISO} > 3.135 V$ |
| Efficiency at $I_{ISO (MAX)}$ | | | 27 | | % | $I_{ISO} = 18 mA$ |
| I_{DDP} , No V_{ISO} Load | $I_{DDP (Q)}$ | | 3.3 | 10.5 | mA | |
| I_{DDP} , Full V_{ISO} Load | $I_{DDP (MAX)}$ | | 77 | | mA | |
| Thermal Shutdown | | | | | | |
| Shutdown Temperature | | | 154 | | °C | |
| Thermal Hysteresis | | | 10 | | °C | |

Table 8. Data Channel Supply Current

| Parameter | Symbol | 1 Mbps—A, B, C Grades | | | 25 Mbps—B, C Grades | | | 100 Mbps—C Grade | | | Unit | Test Conditions/Comments |
|----------------|-----------|-----------------------|-----|-----|---------------------|-----|-----|------------------|-----|-----|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SUPPLY CURRENT | | | | | | | | | | | | |
| ADuM5210 | I_{DD1} | 0.75 | 1.4 | | 5.1 | 9.0 | | 17 | 23 | | mA | $C_L = 0 pF$ |
| | I_{DD2} | 2.0 | 3.5 | | 2.7 | 4.6 | | 4.8 | 9 | | mA | $C_L = 0 pF$ |
| ADuM5211 | I_{DD1} | 1.6 | 2.1 | | 3.8 | 5.0 | | 11 | 15 | | mA | $C_L = 0 pF$ |
| | I_{DD2} | 1.7 | 2.3 | | 3.9 | 6.2 | | 11 | 15 | | mA | $C_L = 0 pF$ |
| ADuM5212 | I_{DD1} | 2.0 | 3.5 | | 2.7 | 4.6 | | 4.8 | 9 | | mA | $C_L = 0 pF$ |
| | I_{DD2} | 0.75 | 1.4 | | 5.1 | 9.0 | | 17 | 23 | | mA | $C_L = 0 pF$ |

Table 9. Switching Specifications

| Parameter | Symbol | A Grade | | | B Grade | | | C Grade | | | Unit | Test Conditions/Comments |
|--------------------------|--------------------|---------|-----|-----|---------|-----|-----|---------|-----|-----|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 25 | | | 100 | Mbps | Within PWD limit |
| Propagation Delay | t_{PHL}, t_{PLH} | | | 50 | | | 35 | 22 | 27 | 35 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | 10 | | | 3 | | | 2.5 | ns | $ t_{PLH} - t_{PHL} $ |
| Pulse Width | PW | 1000 | | | 40 | | | 10 | | | ns | Within PWD limit |
| Propagation Delay Skew | t_{PSK} | | | 38 | | | 16 | | | 12 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t_{PSKCD} | | | 5 | | | 3 | | | 2.5 | ns | |
| Opposing Direction | t_{PSKOD} | | | 10 | | | 6 | | | 5 | ns | |
| Jitter | | | | 2 | | | 2 | | | 1 | ns | |

Table 10. Input and Output Characteristics

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|----------------------------|-----------|--------------------------------|--------------------------------|----------------------------|------|--|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V_{IH} | $0.7 V_{ISO}, 0.7 V_{DD1}$ | | | V | |
| Logic Low Input Threshold | V_{IL} | | | $0.3 V_{ISO}, 0.3 V_{DD1}$ | V | |
| Logic High Output Voltages | V_{OH} | $V_{DD1} - 0.1, V_{DD2} - 0.1$ | V_{DD1}, V_{DD2} | | V | $I_{OX} = -20 \mu A, V_{IX} = V_{IXH}$ |
| | | $V_{DD1} - 0.4, V_{DD2} - 0.4$ | $V_{DD1} - 0.2, V_{DD2} - 0.2$ | | V | $I_{OX} = -3.2 mA, V_{IX} = V_{IXH}$ |
| Logic Low Output Voltages | V_{OL} | | 0.0 | 0.1 | V | $I_{OX} = 20 \mu A, V_{IX} = V_{IXL}$ |
| | | | 0.2 | 0.4 | V | $I_{OX} = 3.2 mA, V_{IX} = V_{IXL}$ |
| Undervoltage Lockout | | | | | | $V_{DD1}, V_{DD2}, V_{DDP}$ supply |
| Positive Going Threshold | V_{UV+} | | 2.6 | | V | |

SPECIFICATIONS

Table 10. Input and Output Characteristics (Continued)

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------|-----|-------|-----|-------------|--|
| Negative Going Threshold | V_{UV-} | | 2.4 | | V | |
| Hysteresis | V_{UVH} | | 0.2 | | V | |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | $I_{DDI(Q)}$ | | 0.4 | 0.6 | mA | |
| Quiescent Output Supply Current | $I_{DDO(Q)}$ | | 1.2 | 1.7 | mA | |
| Dynamic Input Supply Current | $I_{DDI(D)}$ | | 0.08 | | mA/Mbps | |
| Dynamic Output Supply Current | $I_{DDO(D)}$ | | 0.015 | | mA/Mbps | |
| Input Currents per Channel | I_I | -10 | +0.01 | +10 | μ A | $0\text{ V} \leq V_{IX} \leq V_{DDx}$ |
| AC SPECIFICATIONS | | | | | | |
| Output Rise/Fall Time | t_R/t_F | | 3 | | ns | 10% to 90% |
| Common-Mode Transient Immunity ¹ | CM | 25 | 35 | | kV/ μ s | $V_{IX} = V_{DD1}$ or V_{ISO} , $V_{CM} = 1000\text{ V}$, transient magnitude = 800 V |
| Refresh Rate | t_r | | 1.6 | | μ s | |

¹ |CM| is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_{OX} > 0.8 \times V_{DD1}$ or $0.8 \times V_{ISO}$ for a high input or $V_{OX} < 0.8 \times V_{DD1}$ or $0.8 \times V_{ISO}$ for a low input. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

ELECTRICAL CHARACTERISTICS—5 V PRIMARY INPUT SUPPLY/3.3 V SECONDARY ISOLATED SUPPLY

All typical specifications are at $T_A = 25^\circ\text{C}$, $V_{DD1} = V_{DDP} = 5\text{ V}$, $V_{DD2} = 3.3\text{ V}$, V_{SEL} resistor network: $R1 = 10\text{ k}\Omega$, $R2 = 16.9\text{ k}\Omega$ between V_{ISO} and GND_{ISO} . Minimum/maximum specifications apply over the entire recommended operation range which is $4.5\text{ V} \leq V_{DD1}$, $V_{DDP} \leq 5.5\text{ V}$, $3.135\text{ V} \leq V_{DD2} \leq 3.6\text{ V}$, and $-40^\circ\text{C} \leq T_A \leq +105^\circ\text{C}$, unless otherwise noted. Switching specifications are tested with $C_L = 15\text{ pF}$ and CMOS signal levels, unless otherwise noted.

Table 11. DC-to-DC Converter Static Specifications

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|----------------------------------|------------------|-------|-----|------|------------------------------|--|
| DC-TO-DC CONVERTER SUPPLY | | | | | | |
| Setpoint | V_{ISO} | 3.135 | 3.3 | 3.51 | V | $I_{ISO} = 15\text{ mA}$, $R1 = 10\text{ k}\Omega$, $R2 = 16.9\text{ k}\Omega$ |
| Thermal Coefficient | $V_{ISO(TC)}$ | | -26 | | $\mu\text{V}/^\circ\text{C}$ | |
| Line Regulation | $V_{ISO(LINE)}$ | | 20 | | mV/V | $I_{ISO} = 15\text{ mA}$, $V_{DDP} = 4.5\text{ V}$ to 5.5 V |
| Load Regulation | $V_{ISO(LOAD)}$ | | 1.3 | 3 | % | $I_{ISO} = 3\text{ mA}$ to 27 mA |
| Output Ripple | $V_{ISO(RIP)}$ | | 50 | | mV p-p | 20 MHz bandwidth, $C_{BO} = 0.1\text{ }\mu\text{F}$ 10 μF , $I_{ISO} = 27\text{ mA}$ |
| Output Noise | $V_{ISO(NOISE)}$ | | 130 | | mV p-p | $C_{BO} = 0.1\text{ }\mu\text{F}$ 10 μF , $I_{ISO} = 27\text{ mA}$ |
| Switching Frequency | f_{OSC} | | 125 | | MHz | |
| Pulse Width Modulation Frequency | f_{PWM} | | 600 | | kHz | |
| Output Supply | $I_{ISO(MAX)}$ | 30 | | | mA | $3.6\text{ V} > V_{ISO} > 3.135\text{ V}$ |
| Efficiency at $I_{ISO(MAX)}$ | | | 24 | | % | $I_{ISO} = 27\text{ mA}$ |
| I_{DDP} , No V_{ISO} Load | $I_{DDP(Q)}$ | | 3.2 | 8 | mA | |
| I_{DDP} , Full V_{ISO} Load | $I_{DDP(MAX)}$ | | 85 | | mA | |
| Thermal Shutdown | | | | | | |
| Shutdown Temperature | | | 154 | | $^\circ\text{C}$ | |
| Thermal Hysteresis | | | 10 | | $^\circ\text{C}$ | |

Table 12. Data Channel Supply Current

| Parameter | Symbol | 1 Mbps—A, B, C Grades | | | 25 Mbps—B, C Grades | | | 100 Mbps—C Grade | | | Unit | Test Conditions/Comments |
|----------------|-----------|-----------------------|-----|-----|---------------------|-----|-----|------------------|-----|-----|------|--------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SUPPLY CURRENT | | | | | | | | | | | | |
| ADuM5210 | I_{DD1} | 1.1 | 1.6 | | 6.2 | 7.0 | | 20 | 25 | | mA | $C_L = 0\text{ pF}$ |
| | I_{DD2} | 2.0 | 3.5 | | 2.7 | 4.6 | | 4.8 | 9.0 | | mA | $C_L = 0\text{ pF}$ |

SPECIFICATIONS

Table 12. Data Channel Supply Current (Continued)

| Parameter | Symbol | 1 Mbps—A, B, C Grades | | | 25 Mbps—B, C Grades | | | 100 Mbps—C Grade | | | Unit | Test Conditions/ Comments |
|-----------|------------------|-----------------------|-----|-----|---------------------|-----|-----|------------------|-----|-----|------|------------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| ADuM5211 | I _{DD1} | 2.1 | 2.7 | | 4.9 | 6.5 | | 15 | 19 | | mA | C _L = 0 pF |
| | I _{DD2} | 1.7 | 2.3 | | 3.9 | 6.2 | | 11 | 15 | | mA | C _L = 0 pF |
| ADuM5212 | I _{DD1} | 2.0 | 3.5 | | 2.7 | 4.6 | | 4.8 | 9.0 | | mA | C _L = 0 pF |
| | I _{DD2} | 1.1 | 1.6 | | 6.2 | 7.0 | | 20 | 25 | | mA | C _L = 0 pF |

Table 13. Switching Specifications

| Parameter | Symbol | A Grade | | | B Grade | | | C Grade | | | Unit | Test Conditions/ Comments |
|--------------------------|-------------------------------------|---------|-----|-----|---------|-----|-----|---------|-----|-----|------|-------------------------------------|
| | | Min | Typ | Max | Min | Typ | Max | Min | Typ | Max | | |
| SWITCHING SPECIFICATIONS | | | | | | | | | | | | |
| Data Rate | | | | 1 | | | 25 | | | 100 | Mbps | Within PWD limit |
| Propagation Delay | t _{PHL} , t _{PLH} | | | 50 | | | 35 | 20 | 25 | 31 | ns | 50% input to 50% output |
| Pulse Width Distortion | PWD | | | 10 | | | 3 | | | 2.5 | ns | t _{PLH} - t _{PHL} |
| Pulse Width | PW | 1000 | | | 40 | | | 10 | | | ns | Within PWD limit |
| Propagation Delay Skew | t _{PSK} | | | 38 | | | 16 | | | 12 | ns | Between any two units |
| Channel Matching | | | | | | | | | | | | |
| Codirectional | t _{PSKCD} | | | 5 | | | 3 | | | 2 | ns | |
| Opposing Direction | t _{PSKOD} | | | 10 | | | 6 | | | 5 | ns | |
| Jitter | | | 2 | | | 2 | | | 1 | | ns | |

Table 14. Input and Output Characteristics

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|---|--------------------------------|--|--|---|---------|--|
| DC SPECIFICATIONS | | | | | | |
| Logic High Input Threshold | V _{IH} | 0.7 V _{ISO} , 0.7 V _{DD1} | | | V | |
| Logic Low Input Threshold | V _{IL} | | | 0.3 V _{ISO} , 0.3 V _{DD1} | V | |
| Logic High Output Voltages | V _{OH} | V _{DD1} - 0.1, V _{DD2} - 0.1 | V _{DD1} , V _{DD2} | | V | I _{Ox} = -20 μA, V _{Ix} = V _{IxH} |
| | | V _{DD1} - 0.4, V _{DD2} - 0.4 | V _{DD1} - 0.2, V _{DD2} - 0.2 | | V | I _{Ox} = -3.2 mA, V _{Ix} = V _{IxH} |
| Logic Low Output Voltages | V _{OL} | | 0.0 | 0.1 | V | I _{Ox} = 20 μA, V _{Ix} = V _{IxL} |
| | | | 0.2 | 0.4 | V | I _{Ox} = 3.2 mA, V _{Ix} = V _{IxL} |
| Undervoltage Lockout | | | | | | V _{DD1} , V _{DD2} , V _{DDP} supply |
| Positive Going Threshold | V _{UV+} | | 2.6 | | V | |
| Negative Going Threshold | V _{UV-} | | 2.4 | | V | |
| Hysteresis | V _{UVH} | | 0.2 | | V | |
| Supply Current per Channel | | | | | | |
| Quiescent Input Supply Current | I _{DDI(Q)} | | 0.54 | 0.75 | mA | |
| Quiescent Output Supply Current | I _{DDO(Q)} | | 1.2 | 2.0 | mA | |
| Dynamic Input Supply Current | I _{DDI(D)} | | 0.09 | | mA/Mbps | |
| Dynamic Output Supply Current | I _{DDO(D)} | | 0.02 | | mA/Mbps | |
| Input Currents per Channel | I _I | -10 | +0.01 | +10 | μA | 0 V ≤ V _{Ix} ≤ V _{DDx} |
| AC SPECIFICATIONS | | | | | | |
| Output Rise/Fall Time | t _R /t _F | | 2.5 | | ns | 10% to 90% |
| Common-Mode Transient Immunity ¹ | CM | 25 | 35 | | kV/μs | V _{Ix} = V _{DD1} or V _{ISO} , V _{CM} = 1000 V, transient magnitude = 800 V |
| Refresh Rate | t _r | | 1.6 | | μs | |

SPECIFICATIONS

¹ |CM| is the maximum common-mode voltage slew rate that can be sustained while maintaining $V_{Ox} > 0.8 \times V_{DD1}$ or $0.8 \times V_{ISO}$ for a high input or $V_{Ox} < 0.8 \times V_{DD1}$ or $0.8 \times V_{ISO}$ for a low input. The common-mode voltage slew rates apply to both rising and falling common-mode voltage edges.

PACKAGE CHARACTERISTICS

Table 15. Thermal and Isolation Characteristics

| Parameter | Symbol | Min | Typ | Max | Unit | Test Conditions/Comments |
|--|---------------|-----|------------------|-----|----------------------|--|
| Resistance (Input to Output) ¹ | R_{I-O} | | 10 ¹² | | Ω | |
| Capacitance (Input to Output) ¹ | C_{I-O} | | 2.2 | | pF | f = 1 MHz |
| Input Capacitance ² | C_I | | 4.0 | | pF | |
| IC Junction-to-Ambient Thermal Resistance | θ_{JA} | | 50 | | $^{\circ}\text{C/W}$ | Thermocouple located at center of package underside, test conducted on 4-layer board with thin traces ³ |

¹ The device is considered a 2-terminal device: Pin 1 through Pin 10 are shorted together, and Pin 11 through Pin 20 are shorted together.

² Input capacitance is from any input data pin to ground.

³ See the [Thermal Analysis](#) section for thermal model definitions.

REGULATORY INFORMATION

The ADuM5210/ADuM5211/ADuM5212 certification approvals are listed in [Table 16](#).

Table 16.

| UL | CSA | VDE | CQC |
|-------------------------------|--|--|--------------------------------|
| UL 1577 ¹ | IEC/CSA 62368-1 Basic insulation, 530 V rms | DIN EN IEC 60747-17 (VDE 0884-17) ² | CQC GB 4943.1 |
| Single Protection, 2500 V rms | IEC/CSA 61010-1 Basic Insulation, 300 V rms, overvoltage category II | Reinforced insulation, 600 V peak | Basic insulation, 400 V rms |
| File E214100 | File No. 205078 | Certificate No. 40051926 | Certificate No. CQC18001192416 |

¹ In accordance with UL 1577, each ADuM5210/ADuM5211/ADuM5212 is proof tested by applying an insulation test voltage ≥ 3000 V rms for 1 second (current leakage detection limit = 10 μA).

² In accordance with DIN EN IEC 60747-17 (VDE 0884-17), each ADuM5210/ADuM5211/ADuM5212 is proof tested by applying an insulation test voltage ≥ 1590 V peak for 1 second (partial discharge detection limit = 5 pC). The * marking branded on the component designates DIN EN IEC 60747-17 (VDE 0884-17) approval.

INSULATION AND SAFETY-RELATED SPECIFICATIONS

Table 17. Critical Safety-Related Dimensions and Material Properties

| Parameter | Symbol | Value | Unit | Test Conditions/Comments |
|---|--------|-------|---------------|--|
| Rated Dielectric Insulation Voltage | | 2500 | V rms | 1-minute duration |
| Minimum External Air Gap (Clearance) ^{1, 2} | L(I01) | 5.3 | mm | Measured from input terminals to output terminals, shortest distance through air |
| Minimum External Tracking (Creepage) ¹ | L(I02) | 5.3 | mm | Measured from input terminals to output terminals, shortest distance path along body |
| Minimum Internal Gap (Internal Clearance) | | 18 | μm | Distance through insulation |
| Tracking Resistance (Comparative Tracking Index) ³ | CTI | >600 | V | DIN IEC 112/VDE 0303, Part 1 |
| Material Group | | I | | Material group (DIN VDE 0110, 1/89, Table 1) |

¹ In accordance with IEC 62368-1 guidelines for the measurement of creepage and clearance distances for a pollution degree of 2 and altitudes ≤ 2000 m.

² Consideration must be given to pad layout to ensure the minimum required distance for clearance is maintained.

³ CTI rating for the ADuM5210/ADuM5211/ADuM5212 is >600 V and a Material Group I isolation group.

SPECIFICATIONS

DIN EN IEC 60747-17 (VDE 0884-17) INSULATION CHARACTERISTICS

These isolators are suitable for reinforced electrical isolation only within the safety limit data. Maintenance of the safety data is ensured by the protective circuits. The asterisk (*) marking on packages denotes DIN EN IEC 60747-17 (VDE 0884-17) approval.

Table 18. VDE Characteristics

| Description | Test Conditions/Comments | Symbol | Characteristic | Unit |
|---|--|--------------------|--------------------------------|--------|
| Installation Classification per DIN VDE 0110 For Rated Mains Voltage ≤ 150 V rms For Rated Mains Voltage ≤ 300 V rms For Rated Mains Voltage ≤ 400 V rms | | | I to IV I to III I to II | |
| Climatic Classification | | | 40/105/21 | |
| Pollution Degree per DIN VDE 0110, Table 1 | | | 2 | |
| Maximum Repetitive Isolation Voltage | | V _{IORM} | 600 | V peak |
| Maximum Working Insulation Voltage | | V _{IOWM} | 424 | V rms |
| Input-to-Output Test Voltage, Method b1 | V _{IORM} × 1.875 = V _{pd(m)} , 100% production test, t _{ini} = t _m = 1 sec, partial discharge < 5 pC | V _{pd(m)} | 1050 | V peak |
| Input-to-Output Test Voltage, Method a After Environmental Tests Subgroup 1 | V _{IORM} × 1.6 = V _{pd(m)} , t _{ini} = 60 sec, t _m = 10 sec, partial discharge < 5 pC | V _{pd(m)} | 896 | V peak |
| After Input and/or Safety Test Subgroup 2 and Subgroup 3 | V _{IORM} × 1.2 = V _{pd(m)} , t _{ini} = 60 sec, t _m = 10 sec, partial discharge < 5 pC | V _{pd(m)} | 672 | V peak |
| Maximum Transient Isolation Voltage | | V _{IOTM} | 3535 | V peak |
| Maximum Impulse Voltage | Tested in air, 1.2 μs/50 μs waveform per IEC 61000-4-5 | V _{IMP} | 3535 | V peak |
| Maximum Surge Isolation Voltage | Tested in oil, 1.2 μs/50 μs waveform per IEC 61000-4-5, V _{TEST} = V _{IMP} × 1.3 OR ≥ 10 kV | V _{IOSM} | 10000 | V peak |
| Safety Limiting Values | Maximum value allowed in the event of a failure (see Figure 2) | | | |
| Case Temperature | | T _S | 150 | °C |
| Safety Total Dissipated Power | | I _{S1} | 2.5 | W |
| Insulation Resistance at T _S | V _{IO} = 500 V | R _S | >10 ⁹ | Ω |

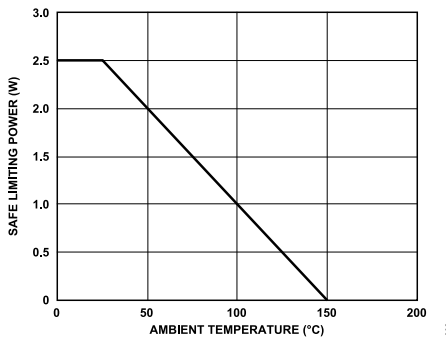


Figure 2. Thermal Derating Curve, Dependence of Safety Limiting Values on Case Temperature, per DIN EN IEC 60747-17 (VDE 0884-17)

SPECIFICATIONS

RECOMMENDED OPERATING CONDITIONS

Table 19.

| Parameter | Symbol | Min | Max | Unit |
|---|--------------------|-------|------|------|
| Operating Temperature ¹ | T_A | -40 | +105 | °C |
| Supply Voltages ² | | | | |
| V_{DDP} at $V_{ISO} = 3.135\text{ V to }3.6\text{ V}$ | V_{DDP} | 3.135 | 5.5 | V |
| V_{DDP} at $V_{ISO} = 4.5\text{ V to }5.5\text{ V}$ | | 4.5 | 5.5 | V |
| V_{DD1}, V_{DD2} | V_{DD1}, V_{DD2} | 3.135 | 5.5 | V |

¹ Operation at 105°C requires reduction of the maximum load current as specified in Table 20.

² Each voltage is relative to its respective ground.

ABSOLUTE MAXIMUM RATINGS

Ambient temperature = 25°C, unless otherwise noted.

Table 20.

| Parameter | Rating |
|--|--|
| Storage Temperature (T_{ST}) | -55°C to +150°C |
| Ambient Operating Temperature (T_A) | -40°C to +105°C |
| Supply Voltages (V_{DDP} , V_{DD1} , V_{DD2} , V_{ISO}) ¹ | -0.5 V to +7.0 V |
| V_{ISO} Supply Current ² | |
| $T_A = -40^\circ\text{C}$ to $+105^\circ\text{C}$ | 30 mA |
| Input Voltage (V_{IA} , V_{IB} , $PDIS$, V_{SEL}) ^{1,3} | -0.5 V to $V_{DDI} + 0.5$ V |
| Output Voltage (V_{OA} , V_{OB}) ^{1,3} | -0.5 V to $V_{DDO} + 0.5$ V |
| Average Output Current Per Data Output Pin ⁴ | -10 mA to +10 mA |
| Common-Mode Transients ⁵ | -100 kV/ μs to +100 kV/ μs |

¹ All voltages are relative to their respective ground.

² The V_{ISO} provides current for dc and dynamic loads on the V_{ISO} I/O channels. This current must be included when determining the total V_{ISO} supply current. For ambient temperatures between 85°C and 105°C, maximum allowed current is reduced.

³ V_{DDI} and V_{DDO} refer to the supply voltages on the input and output sides of a given channel, respectively. See the [PCB Layout](#) section.

⁴ See [Figure 2](#) for the maximum rated current values for various temperatures.

⁵ Refers to common-mode transients across the insulation barrier. Common-mode transients exceeding the absolute maximum ratings may cause latch-up or permanent damage.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress

rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

Maximum Continuous Working Voltage¹

Table 21.

| Parameter | Max | Unit | Applicable Certification |
|------------------|-----|--------|--|
| AC Voltage | | | |
| Bipolar Waveform | 600 | V peak | Reinforced insulation rating per IEC 60747-17 (VDE 0884-17). |

¹ Refers to the continuous voltage magnitude imposed across the isolation barrier. See the [Insulation Lifetime](#) section for more information.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

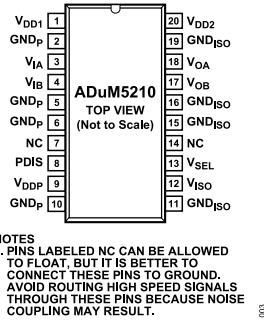


Figure 3. ADuM5210 Pin Configuration

Table 22. ADuM5210 Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|----------------|--------------------|--|
| 1 | V _{DD1} | Power Supply for the Side 1 Logic Circuits of the Device. It is independent of V _{DDP} and can operate between 3.135 V and 5.5 V. |
| 2, 5, 6, 10 | GND _P | Ground Reference for Isolator Side 1. All of these pins are internally connected, and it is recommended that all GND _P pins be connected to a common ground. |
| 3 | V _{IA} | Logic Input A. |
| 4 | V _{IB} | Logic Input B. |
| 7, 14 | NC | This pin is not connected internally (see Figure 3). |
| 8 | PDIS | Power Disable. When this pin is tied to a logic low, the power converter is active; when tied to a logic high, the power supply enters a low power standby mode. |
| 9 | V _{DDP} | Primary isoPower Supply Voltage, 3.135 V to 5.5 V. |
| 11, 15, 16, 19 | GND _{ISO} | Ground Reference for Isolator Side 2. All of these pins are internally connected, and it is recommended that all GND _{ISO} pins be connected to a common ground. |
| 12 | V _{ISO} | Secondary Supply Voltage Output for External Loads, 3.3 V (V _{SEL} Low) or 5.0 V (V _{SEL} High). |
| 13 | V _{SEL} | Output Voltage Select. Provide a thermally matched resistor network between V _{ISO} and GND _{ISO} to divide the required output voltage to match the 1.25 V reference voltage. V _{ISO} voltage can be programmed up to 20% higher or 75% lower than V _{DDP} but must be within the allowed output voltage range. |
| 17 | V _{OB} | Logic Output B. |
| 18 | V _{OA} | Logic Output A. |
| 20 | V _{DD2} | Power Supply for the Side 2 Logic Circuits of the Device. It is independent of V _{ISO} and can operate between 3.135 V and 5.5 V. |

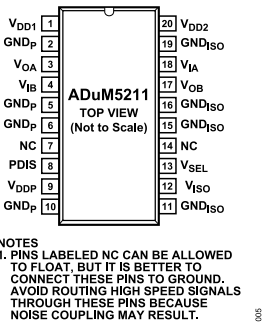


Figure 4. ADuM5211 Pin Configuration

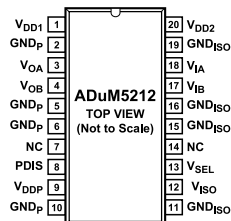
Table 23. ADuM5211 Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|-------------|------------------|---|
| 1 | V _{DD1} | Power Supply for the Side 1 Logic Circuits of the Device. It is independent of V _{DDP} and can operate between 3.135 V and 5.5 V. |
| 2, 5, 6, 10 | GND _P | Ground Reference for Isolator Side 1. All of these pins are internally connected, and it is recommended that all GND _P pins be connected to a common ground. |

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

Table 23. ADuM5211 Pin Function Descriptions (Continued)

| Pin No. | Mnemonic | Description |
|----------------|--------------------|--|
| 3 | V _{OA} | Logic Output A. |
| 4 | V _{IB} | Logic Input B. |
| 7, 14 | NC | This pin is not connected internally (see Figure 4). |
| 8 | PDIS | Power Disable. When this pin is tied to a logic low, the power converter is active; when tied to a logic high, the power supply enters a low power standby mode. |
| 9 | V _{DDP} | Primary isoPower Supply Voltage, 3.135 V to 5.5 V. |
| 11, 15, 16, 19 | GND _{ISO} | Ground Reference for Isolator Side 2. All of these pins are internally connected, and it is recommended that all GND _{ISO} pins be connected to a common ground. |
| 12 | V _{ISO} | Secondary Supply Voltage Output for External Loads, 3.3 V (V _{SEL} Low) or 5.0 V (V _{SEL} High). |
| 13 | V _{SEL} | Output Voltage Select. Provide a thermally matched resistor network between V _{ISO} and GND _{ISO} to divide the required output voltage to match the 1.25 V reference voltage. V _{ISO} voltage can be programmed up to 20% higher or 75% lower than V _{DDP} but must be within the allowed output voltage range. |
| 17 | V _{OB} | Logic Output B. |
| 18 | V _{IA} | Logic Input A. |
| 20 | V _{DD2} | Power Supply for the Side 2 Logic Circuits of the Device. It is independent of V _{ISO} and can operate between 3.135 V and 5.5 V. |



NOTES
 1. PINS LABELED NC CAN BE ALLOWED TO FLOAT OR CAN BE CONNECTED TO THE GROUND. AVOID CONNECTING THEM TO HIGH SPEED SIGNALS TO MINIMIZE CAPACITIVE COUPLING OF NOISE.

Figure 5. ADuM5212 Pin Configuration

Table 24. ADuM5212 Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|----------------|--------------------|--|
| 1 | V _{DD1} | Power Supply for the Side 1 Logic Circuits of the Device. It is independent of V _{DDP} and can operate between 3.135 V and 5.5 V. |
| 2, 5, 6, 10 | GND _P | Ground Reference for Isolator Side 1. All of these pins are internally connected, and it is recommended that all GND _P pins be connected to a common ground. |
| 3 | V _{OA} | Logic Output A. |
| 4 | V _{OB} | Logic Output B. |
| 7, 14 | NC | This pin is not connected internally (see Figure 5). |
| 8 | PDIS | Power Disable. When this pin is tied to a logic low, the power converter is active; when tied to a logic high, the power supply enters a low power standby mode. |
| 9 | V _{DDP} | Primary isoPower Supply Voltage, 3.135 V to 5.5 V. |
| 11, 15, 16, 19 | GND _{ISO} | Ground Reference for Isolator Side 2. All of these pins are internally connected, and it is recommended that all GND _{ISO} pins be connected to a common ground. |
| 12 | V _{ISO} | Secondary Supply Voltage Output for External Loads, 3.3 V (V _{SEL} Low) or 5.0 V (V _{SEL} High). |
| 13 | V _{SEL} | Output Voltage Select. Provide a thermally matched resistor network between V _{ISO} and GND _{ISO} to divide the required output voltage to match the 1.25 V reference voltage. V _{ISO} voltage can be programmed up to 20% higher or 75% lower than V _{DDP} but must be within the allowed output voltage range. |
| 17 | V _{IB} | Logic Input B. |
| 18 | V _{IA} | Logic Input A. |
| 20 | V _{DD2} | Power Supply for the Side 2 Logic Circuits of the Device. It is independent of V _{ISO} and can operate between 3.135 V and 5.5 V. |

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

TRUTH TABLE

Table 25. Power Section Truth Table (Positive Logic)

| V _{DDP} (V) | V _{SEL} Input | PDIS Input | V _{ISO} Output (V) | Notes |
|----------------------|--------------------------|------------|-----------------------------|-------------------------------|
| 5 | R1 = 10 kΩ, R2 = 30.9 kΩ | Low | 5 | |
| 5 | R1 = 10 kΩ, R2 = 30.9 kΩ | High | 0 | |
| 3.3 | R1 = 10 kΩ, R2 = 16.9 kΩ | Low | 3.3 | |
| 3.3 | R1 = 10 kΩ, R2 = 16.9 kΩ | High | 0 | |
| 5 | R1 = 10 kΩ, R2 = 16.9 kΩ | Low | 3.3 | |
| 5 | R1 = 10 kΩ, R2 = 16.9 kΩ | High | 0 | |
| 3.3 | R1 = 10 kΩ, R2 = 30.9 kΩ | Low | 5 | Configuration not recommended |
| 3.3 | R1 = 10 kΩ, R2 = 30.9 kΩ | High | 0 | |

Table 26. Data Section Truth Table (Positive Logic)

| V _{DDI} State ¹ | V _{Ix} Input ¹ | V _{DDO} State ¹ | V _{Ox} Output ¹ | Notes |
|-------------------------------------|------------------------------------|-------------------------------------|-------------------------------------|--|
| Powered | High | Powered | High | Normal operation, data is high |
| Powered | Low | Powered | Low | Normal operation, data is low |
| X ² | X ² | Unpowered | Z ³ | Output is off |
| Unpowered | Low | Powered | Low | Output default low |
| Unpowered | High | Powered | Indeterminate | If a high level is applied to an input when no supply is present, then it can parasitically power the input side causing unpredictable operation |

¹ The references to I and O in this table refer to the input side and output side of a given data path and the associated power supply.

² X = don't care.

³ Z = high impedance state.

TYPICAL PERFORMANCE CHARACTERISTICS

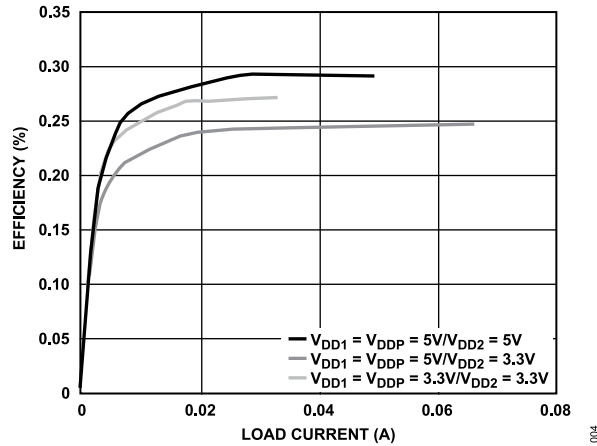


Figure 6. Typical Power Supply Efficiency at 5 V/5 V, 5 V/3.3 V, and 3.3 V/3.3 V

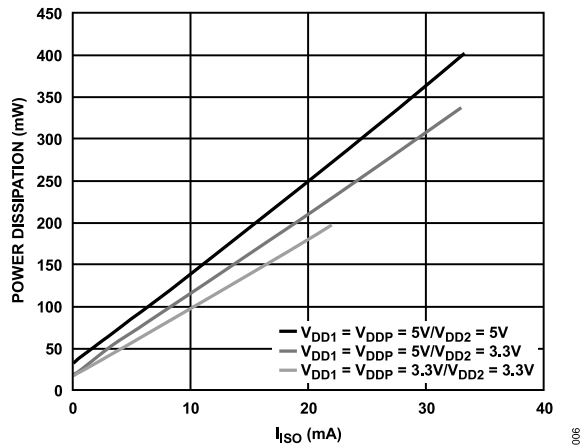


Figure 7. Typical Total Power Dissipation vs. I_{ISO}

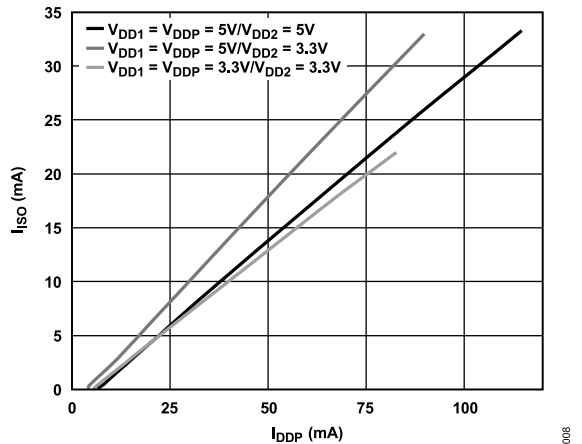


Figure 8. Typical Isolated Output Supply Current, I_{ISO} , as a Function of External Load, at 5 V/5 V, 5 V/3.3 V, and 3.3 V/3.3 V

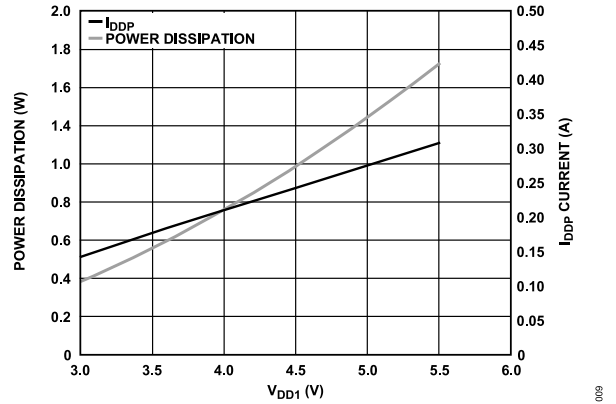


Figure 9. Typical Short-Circuit Input Current and Power vs. V_{DD1} Supply Voltage

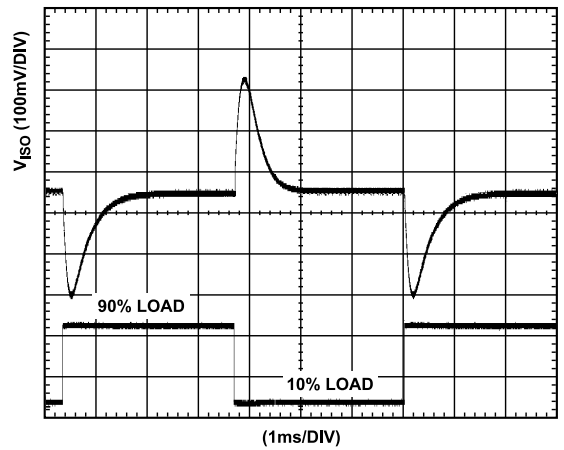


Figure 10. Typical V_{ISO} Transient Load Response, 5 V Output, 10% to 90% Load Step

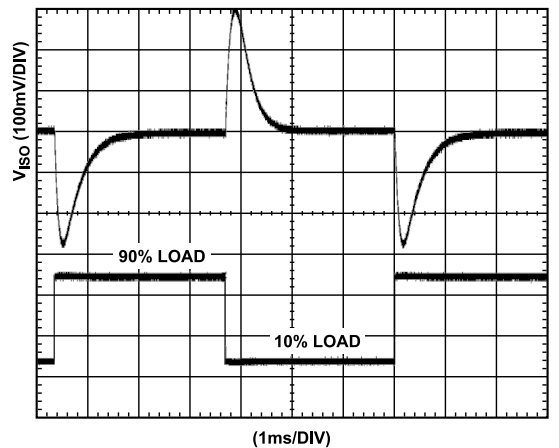


Figure 11. Typical Transient Load Response, 3 V Output, 10% to 90% Load Step

TYPICAL PERFORMANCE CHARACTERISTICS

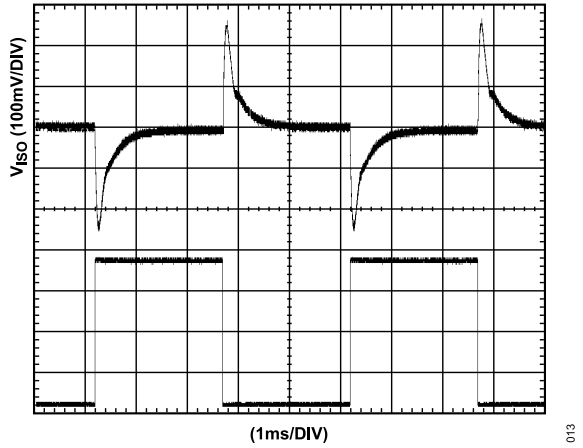


Figure 12. Typical Transient Load Response, 5 V Input, 3.3 V Output, 10% to 90% Load Step

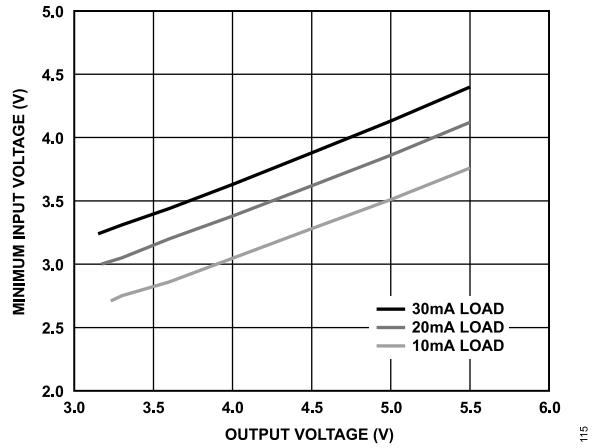


Figure 15. Relationship Between Output Voltage and Required Input Voltage, Under Load, to Maintain >80% Duty Factor in the PWM

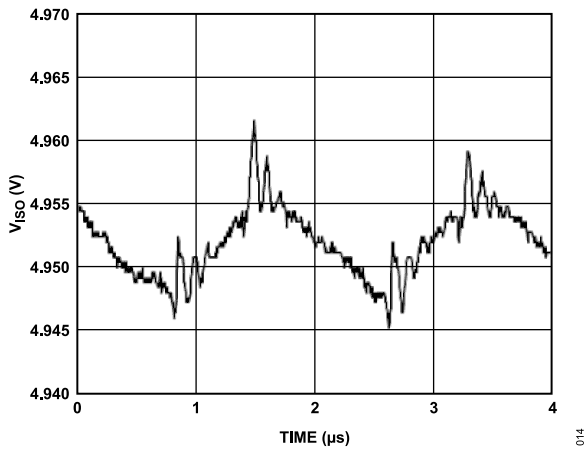


Figure 13. Typical $V_{ISO} = 5\text{ V}$ Output Voltage Ripple at 90% Load

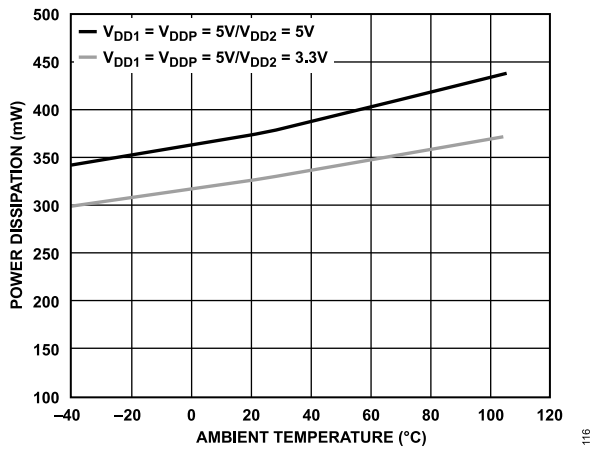


Figure 16. Power Dissipation with a 30 mA Load vs. Temperature

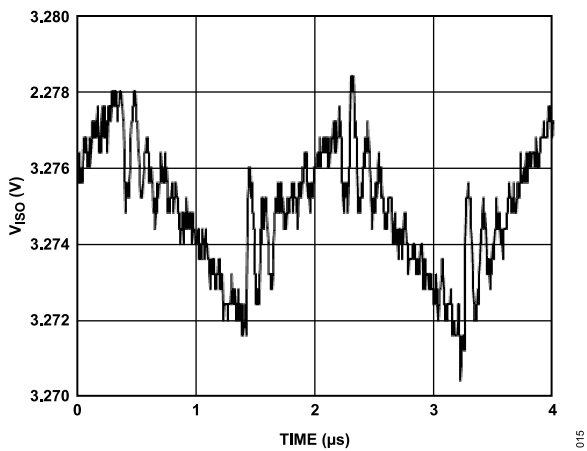


Figure 14. Typical $V_{ISO} = 3.3\text{ V}$ Output Voltage Ripple at 90% Load

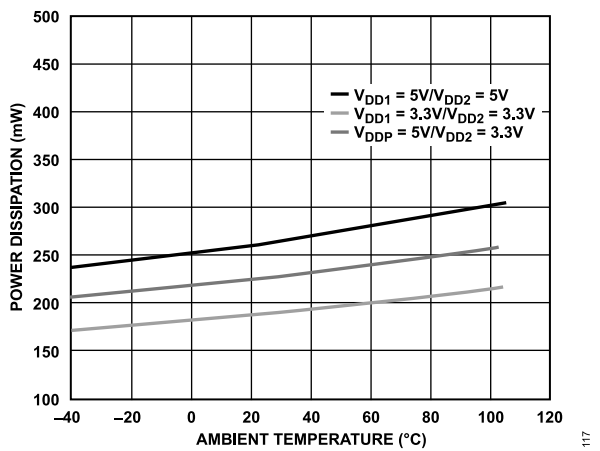


Figure 17. Power Dissipation with a 20 mA Load vs. Temperature

TYPICAL PERFORMANCE CHARACTERISTICS

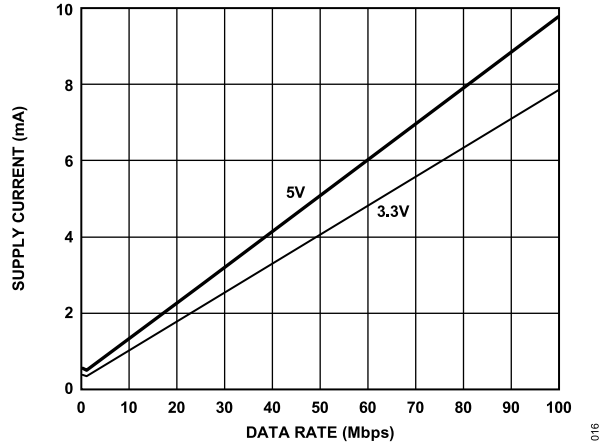


Figure 18. Typical Supply Current per Input Channel vs. Data Rate for 5 V and 3.3 V Operation

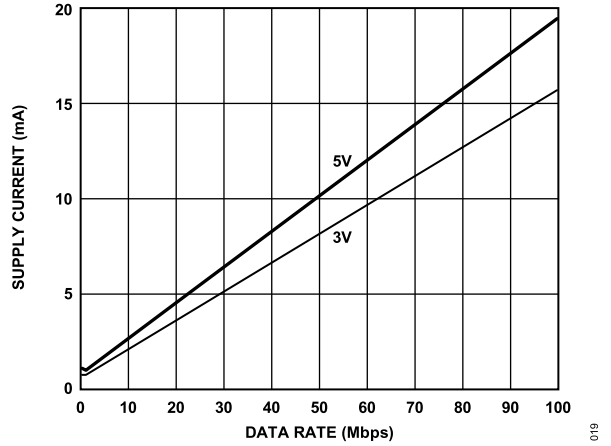


Figure 21. Typical ADuM5210 V_{DD1} or ADuM5212 V_{DD2} Supply Current vs. Data Rate for 5 V and 3.3 V Operation

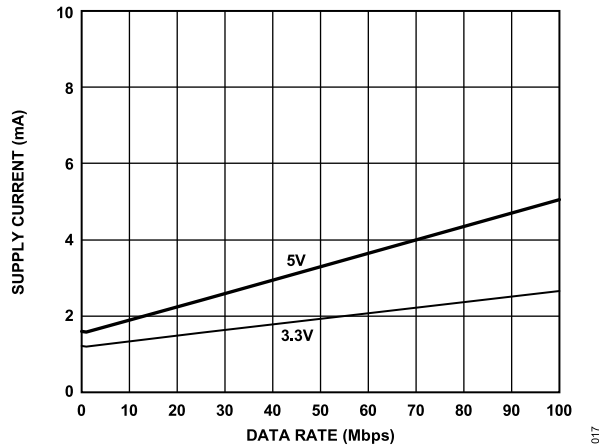


Figure 19. Typical Supply Current per Output Channel vs. Data Rate for 5 V and 3.3 V Operation (No Output Load)

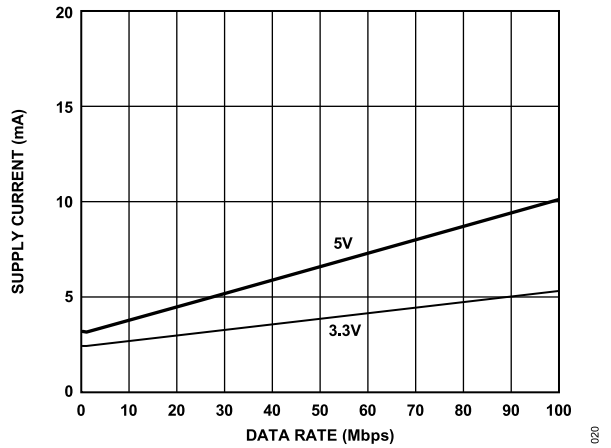


Figure 22. Typical ADuM5210 V_{DD2} or ADuM5212 V_{DD2} Supply Current vs. Data Rate for 5 V and 3.3 V Operation

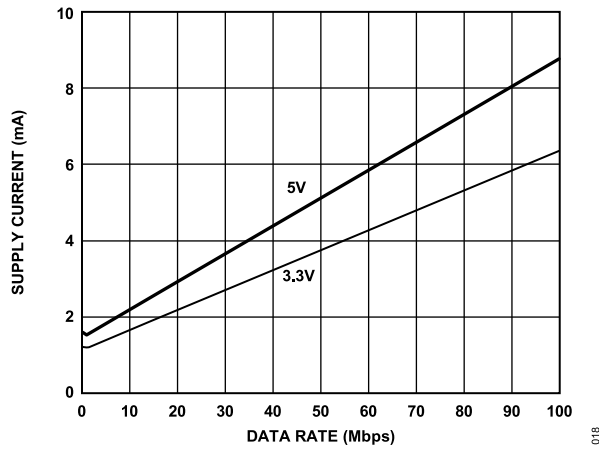


Figure 20. Typical Supply Current per Output Channel vs. Data Rate for 5 V and 3.3 V Operation (15 pF Output Load)

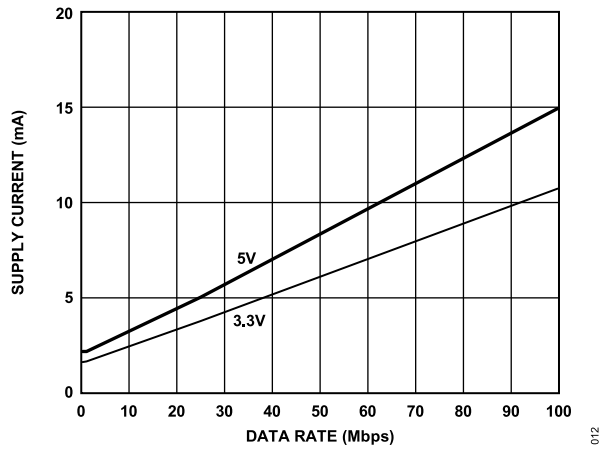


Figure 23. Typical ADuM5211 V_{DD1} or V_{DD2} Supply Current vs. Data Rate for 5 V and 3.3 V Operation

APPLICATIONS INFORMATION

The dc-to-dc converter section of the ADuM5210/ADuM5211/ADuM5212 works on principles that are common to most modern power supplies. It has a split controller architecture with isolated pulse-width modulation (PWM) feedback. V_{DDP} power is supplied to an oscillating circuit that switches current into a chip-scale air core transformer. Power transferred to the secondary side is rectified and regulated to a value between 3.135 V and 5.25 V, depending on the setpoint supplied by an external voltage divider (see Equation 1). The secondary (V_{ISO}) side controller regulates the output by creating a PWM control signal that is sent to the primary (V_{DDP}) side by a dedicated *iCoupler* data channel. The PWM modulates the oscillator circuit to control the power being sent to the secondary side. Feedback allows for significantly higher power and efficiency.

$$V_{ISO} = 1.25 V \frac{(R1 + R2)}{R1} \quad (1)$$

where:

$R1$ is a resistor between V_{SEL} and GND_{ISO} .

$R2$ is a resistor between V_{SEL} and V_{ISO} .

Because the output voltage can be adjusted continuously there are an infinite number of operating conditions. This data sheet addresses three discrete operating conditions in the Specifications tables. Many other combinations of input and output voltage are possible; Figure 15 depicts the supported voltage combinations at room temperature. Figure 15 was generated by fixing the V_{ISO} load and decreasing the input voltage until the PWM was at 80% duty cycle. Each of the curves represents the minimum input voltage that is required for operation under this criterion. For example, if the application requires 30 mA of output current at 5 V, the minimum input voltage at V_{DDP} is 4.25 V. Figure 15 also illustrates why the $V_{DDP} = 3.3$ V input and $V_{ISO} = 5$ V configuration is not recommended. Even at 10 mA of output current, the PWM cannot maintain less than 80% duty factor, leaving no margin to support load or temperature variations.

Typically, the ADuM5210/ADuM5211/ADuM5212 dissipate about 17% more power between room temperature and maximum temperature; therefore, the 20% PWM margin covers temperature variations.

The ADuM5210/ADuM5211/ADuM5212 implement undervoltage lockout (UVLO) with hysteresis on the primary and secondary side I/O pins as well as the V_{DDP} power input. This feature ensures that the converter does not go into oscillation due to noisy input power or slow power-on ramp rates.

PCB LAYOUT

The ADuM5210/ADuM5211/ADuM5212 digital isolators with 0.15 W *isoPower* integrated dc-to-dc converters require no external interface circuitry for the logic interfaces. Power supply bypassing with a low ESR capacitor is required, as close to the chip pads as possible. The *isoPower* inputs require several passive components to bypass the power effectively as well as set the output voltage

and bypass the core voltage regulator (see Figure 24 through Figure 26).

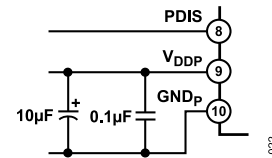


Figure 24. V_{DDP} Bias and Bypass Components

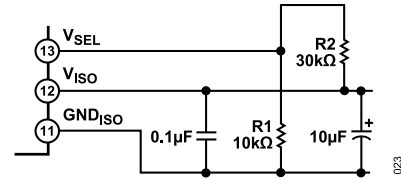


Figure 25. V_{ISO} Bias and Bypass Components

The power supply section of the ADuM5210/ADuM5211/ADuM5212 uses a 125 MHz oscillator frequency to efficiently pass power through its chip-scale transformers. Bypass capacitors are required for several operating frequencies. Noise suppression requires a low inductance, high frequency capacitor; ripple suppression and proper regulation require a large value bulk capacitor. These capacitors are most conveniently connected between Pin 9 and Pin 10 for V_{DDP} and between Pin 11 and Pin 12 for V_{ISO} . To suppress noise and reduce ripple, a parallel combination of at least two capacitors is required. The recommended capacitor values are 0.1 µF and 10 µF for V_{DDP} . The smaller capacitor must have a low ESR; for example, use of an NPO or X5R ceramic capacitor is advised. Ceramic capacitors are also recommended for the 10 µF bulk capacitance. An additional 10 nF capacitor can be added in parallel if further EMI reduction is required.

Note that the total lead length between the ends of the low ESR capacitor and the input power supply pin must not exceed 2 mm.

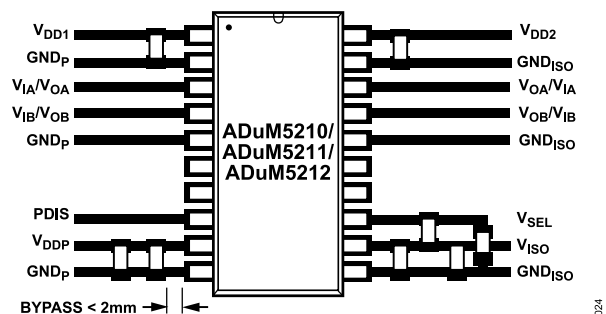


Figure 26. Recommended PCB Layout

In applications involving high common-mode transients, ensure that board coupling across the isolation barrier is minimized. Furthermore, design the board layout such that any coupling that does occur equally affects all pins on a given component side. Failure to ensure this can cause voltage differentials between pins, exceed-

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ing the absolute maximum ratings specified in [Table 20](#), thereby leading to latch-up and/or permanent damage.

THERMAL ANALYSIS

The ADuM5210/ADuM5211/ADuM5212 consist of four internal die attached to a split lead frame with two die attach paddles. For the purposes of thermal analysis, the chip is treated as a thermal unit, with the highest junction temperature reflected in the θ_{JA} from [Table 15](#). The value of θ_{JA} is based on measurements taken with the parts mounted on a JEDEC standard, 4-layer board with fine width traces and still air. Under normal operating conditions, the ADuM5210/ADuM5211/ADuM5212 can operate at full load across the full temperature range without derating the output current.

PROPAGATION DELAY PARAMETERS

Propagation delay is a parameter that describes the time it takes a logic signal to propagate through a component (see [Figure 27](#)). The propagation delay to a logic low output may differ from the propagation delay to a logic high.

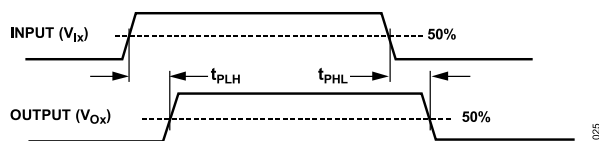


Figure 27. Propagation Delay Parameters

Pulse width distortion is the maximum difference between these two propagation delay values and is an indication of how accurately the input signal timing is preserved.

Channel-to-channel matching refers to the maximum amount the propagation delay differs between channels within a single ADuM5210/ADuM5211/ADuM5212 component.

Propagation delay skew refers to the maximum amount the propagation delay differs between multiple ADuM5210/ADuM5211/ADuM5212 devices operating under the same conditions.

EMI CONSIDERATIONS

The dc-to-dc converter section of the ADuM5210/ADuM5211/ADuM5212 components must, of necessity, operate at a very high frequency to allow efficient power transfer through the small transformers. This creates high frequency currents that can propagate in circuit board ground and power planes, causing edge and dipole radiation. Grounded enclosures are recommended for applications that use these devices. If grounded enclosures are not possible, follow good RF design practices in the layout of the PCB. See the [AN-0971 Application Note](#) for the most current PCB layout recommendations for the ADuM5210/ADuM5211/ADuM5212.

DC CORRECTNESS AND MAGNETIC FIELD IMMUNITY

Positive and negative logic transitions at the isolator input cause narrow (~1 ns) pulses to be sent to the decoder via the transformer.

The decoder is bistable and is, therefore, either set or reset by the pulses, indicating input logic transitions. In the absence of logic transitions at the input for more than 1.6 μ s, periodic sets of refresh pulses indicative of the correct input state are sent to ensure dc correctness at the output. If the decoder receives no internal pulses of more than approximately 6.4 μ s, the input side is assumed to be unpowered or nonfunctional, in which case, the isolator output is forced to a default low state by the watchdog timer circuit. This situation should occur in the ADuM5210/ADuM5211/ADuM5212 only during power-up and power-down operations.

The limitation on the ADuM5210/ADuM5211/ADuM5212 magnetic field immunity is set by the condition in which induced voltage in the transformer receiving coil is sufficiently large to either falsely set or reset the decoder. The following analysis defines the conditions under which this can occur. The 3.3 V operating condition of the ADuM5210/ADuM5211/ADuM5212 is examined because it represents the most susceptible mode of operation.

The pulses at the transformer output have an amplitude of >1.5 V. The decoder has a sensing threshold of about 0.5 V, thus establishing a 0.5 V margin in which induced voltages can be tolerated. The voltage induced across the receiving coil is given by

$$V = (-d\beta/dt) \sum \pi r_n^2; n = 1, 2, \dots, N \quad (2)$$

where:

β is the magnetic flux density (gauss).

N is the number of turns in the receiving coil.

r_n is the radius of the n^{th} turn in the receiving coil (cm).

Given the geometry of the receiving coil in the ADuM5210/ADuM5211/ADuM5212 and an imposed requirement that the induced voltage be, at most, 50% of the 0.5 V margin at the decoder, a maximum allowable magnetic field is calculated as shown in [Figure 28](#).

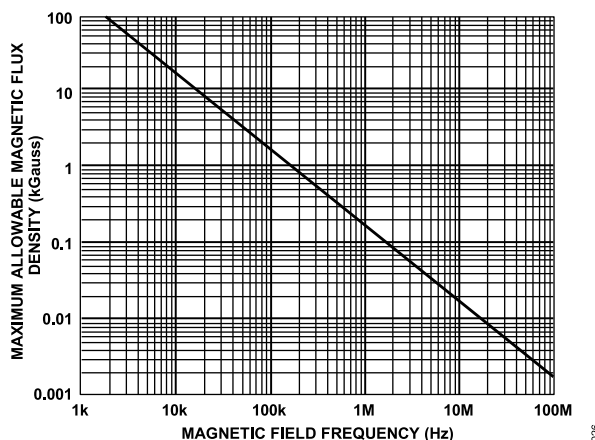


Figure 28. Maximum Allowable External Magnetic Flux Density

For example, at a magnetic field frequency of 1 MHz, the maximum allowable magnetic field of 0.2 kgauss induces a voltage of 0.25 V at the receiving coil. This is about 50% of the sensing threshold and does not cause a faulty output transition. Similarly, if such an event

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occurs during a transmitted pulse (and is of the worst-case polarity), it reduces the received pulse from >1.0 V to 0.75 V, which is still well above the 0.5 V sensing threshold of the decoder.

The preceding magnetic flux density values correspond to specific current magnitudes at given distances from the ADuM5210/ADuM5211/ADuM5212 transformers. Figure 29 expresses these allowable current magnitudes as a function of frequency for selected distances. As shown in Figure 29, the ADuM5210/ADuM5211/ADuM5212 are extremely immune and can be affected only by extremely large currents operated at high frequency very close to the component. For the 1 MHz example, a 0.5 kA current, placed 5 mm away from the ADuM5210/ADuM5211/ADuM5212, is required to affect component operation.

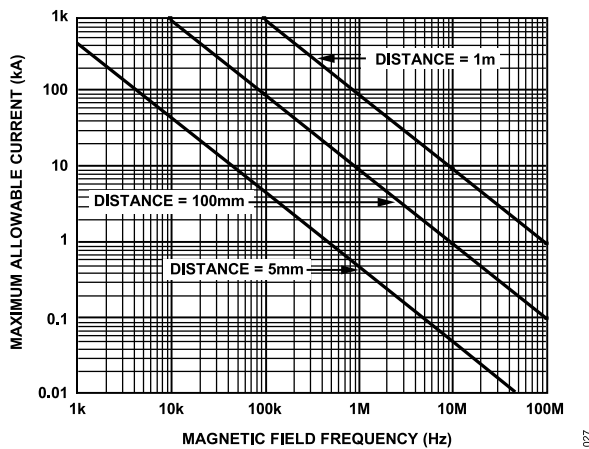


Figure 29. Maximum Allowable Current for Various Current-to-ADuM521x Spacings

Note that, in combinations of strong magnetic field and high frequency, any loops formed by PCB traces can induce error voltages sufficiently large to trigger the thresholds of succeeding circuitry. Exercise care in the layout of such traces to avoid this possibility.

POWER CONSUMPTION

The V_{DDP} power supply input provides power only to the converter. Power for the data channels is provided through V_{DD1} and V_{DD2} . These power supplies can be connected to V_{DDP} and V_{ISO} , if desired, or the supplies can receive power from an independent source. The converter should be treated as a standalone supply to be utilized at the discretion of the designer.

The V_{DD1} or V_{DD2} supply current at a given channel of the ADuM5210/ADuM5211/ADuM5212 isolator is a function of the supply voltage, the data rate of the channel, and the output load of the channel.

For each input channel, the supply current is given by

$$I_{DDI} = I_{DDI(Q)} f \leq 0.5 f_r \quad (3)$$

$$I_{DDI} = I_{DDI(D)} \times (2f - f_r) + I_{DDI(Q)} f > 0.5 f_r \quad (4)$$

For each output channel, the supply current is given by

$$I_{DDO} = I_{DDO(Q)} f \leq 0.5 f_r \quad (5)$$

$$I_{DDO} = (I_{DDO(D)} + (0.5 \times 10^{-3}) \times C_L \times V_{DDO}) \times (2f - f_r) + I_{DDO(Q)} f > 0.5 f_r \quad (6)$$

where:

$I_{DDI(D)}$, $I_{DDO(D)}$ are the input and output dynamic supply currents per channel (mA/Mbps).

$I_{DDI(Q)}$, $I_{DDO(Q)}$ are the specified input and output quiescent supply currents (mA).

f is the input logic signal frequency (MHz); it is half the input data rate, expressed in units of Mbps.

f_r is the input stage refresh rate (Mbps).

C_L is the output load capacitance (pF).

V_{DDO} is the output supply voltage (V).

To calculate the total V_{DD1} and V_{DD2} supply current, the supply currents for each input and output channel corresponding to V_{DD1} and V_{DD2} are calculated and totaled. Figure 18 and Figure 19 show per-channel supply currents as a function of data rate for an unloaded output condition. Figure 20 shows the per-channel supply current as a function of data rate for a 15 pF output condition. Figure 21 through Figure 23 show the total V_{DD1} and V_{DD2} supply current as a function of data rate for ADuM5210/ADuM5211/ADuM5212 channel configurations.

INSULATION LIFETIME

All insulation structures eventually break down when subjected to voltage stress over a sufficiently long period. The rate of insulation degradation is dependent on the characteristics of the voltage waveform applied across the insulation. Analog Devices conducts an extensive set of evaluations to determine the lifetime of the insulation structure within the ADuM5210/ADuM5211/ADuM5212.

Accelerated life testing is performed using voltage levels higher than the rated continuous working voltage. Acceleration factors for several operating conditions are determined, allowing calculation of the time to failure at the working voltage of interest. The values shown in Table 21 summarize the maximum continuous working voltages as per IEC 60747-17. Operation at working voltages higher than the service life voltage listed leads to premature insulation failure.

OUTLINE DIMENSIONS

| Package Drawing (Option) | Package Type | Package Description |
|--------------------------|--------------|--------------------------------------|
| RS-20 | SSOP | 20-Lead Shrink Small Outline Package |

For the latest package outline information and land patterns (footprints), go to [Package Index](#).

ORDERING GUIDE

| Model ^{1,2} | Temperature Range (°C) | Package Description | Package Option |
|----------------------|------------------------|---------------------|----------------|
| ADuM5210ARSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5210ARSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5210BRSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5210BRSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5210CRSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5210CRSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5211ARSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5211ARSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5211BRSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5211BRSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5211CRSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5211CRSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5212ARSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5212ARSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5212BRSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5212BRSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5212CRSZ | -40 to +105 | 20-Lead SSOP | RS-20 |
| ADuM5212CRSZ-RL7 | -40 to +105 | 20-Lead SSOP | RS-20 |

¹ The addition of an RL7 suffix designates a 7" tape and reel option.

² Z = RoHS Compliant Part.

NUMBER OF INPUTS, MAXIMUM DATA RATE, MAXIMUM PROPAGATION DELAY, AND MAXIMUM PULSE WIDTH DISTORTION OPTIONS

| Model ¹ | Number of Inputs, V _{DDP} Side | Number of Inputs, V _{ISO} Side | Maximum Data Rate (Mbps) | Maximum Propagation Delay, 5 V (ns) | Maximum Pulse Width Distortion (ns) |
|--------------------|---|---|--------------------------|-------------------------------------|-------------------------------------|
| ADuM5210ARSZ | 2 | 0 | 1 | 75 | 40 |
| ADuM5210ARSZ-RL7 | 2 | 0 | 1 | 75 | 40 |
| ADuM5210BRSZ | 2 | 0 | 25 | 40 | 3 |
| ADuM5210BRSZ-RL7 | 2 | 0 | 25 | 40 | 3 |
| ADuM5210CRSZ | 2 | 0 | 100 | 15 | 2 |
| ADuM5210CRSZ-RL7 | 2 | 0 | 100 | 15 | 2 |
| ADuM5211ARSZ | 1 | 1 | 1 | 75 | 40 |
| ADuM5211ARSZ-RL7 | 1 | 1 | 1 | 75 | 40 |
| ADuM5211BRSZ | 1 | 1 | 25 | 40 | 3 |
| ADuM5211BRSZ-RL7 | 1 | 1 | 25 | 40 | 3 |
| ADuM5211CRSZ | 1 | 1 | 100 | 15 | 2 |
| ADuM5211CRSZ-RL7 | 1 | 1 | 100 | 15 | 2 |
| ADuM5212ARSZ | 0 | 2 | 1 | 75 | 40 |
| ADuM5212ARSZ-RL7 | 0 | 2 | 1 | 75 | 40 |
| ADuM5212BRSZ | 0 | 2 | 25 | 40 | 3 |
| ADuM5212BRSZ-RL7 | 0 | 2 | 25 | 40 | 3 |

OUTLINE DIMENSIONS

| Model ¹ | Number of Inputs, V _{DDP} Side | Number of Inputs, V _{ISO} Side | Maximum Data Rate (Mbps) | Maximum Propagation Delay, 5 V (ns) | Maximum Pulse Width Distortion (ns) |
|--------------------|--|--|-----------------------------|--|--|
| ADuM5212CRSZ | 0 | 2 | 100 | 15 | 2 |
| ADuM5212CRSZ-RL7 | 0 | 2 | 100 | 15 | 2 |

¹ Z=RoHS Compliant Part

EVALUATION BOARDS

| Model ¹ | Package Description |
|--------------------|---------------------|
| EVAL-ADuM5211EBZ | Evaluation Board |

¹ Z = RoHS Compliant Part.

Looking for pricing, stock, or lifecycle information?

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-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management